### SCHOTTKY BARRIER RECTIFIER

VOLTAGE RANGE: 35 --- 200 V CURRENT:15.0A

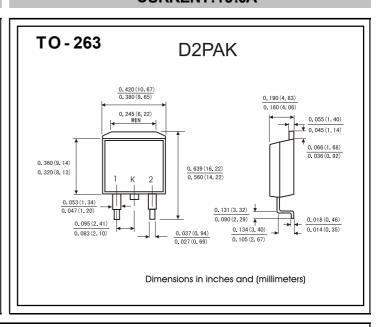
### **FEATURES**

- Metal-semiconductor junction with guard ring

- High surge capability
- For use in low voltage, high frequency inverters free wheeling, and polarity protection applications

### **MECHANICAL DATA**

- ◇Polarity: As marked
- ♦ Weight: 0.08ounces,2.24 grams



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

|  |                        | Symbols        | MBR<br>1535 | MBR<br>1545 | MBR<br>1550 | MBR<br>1560 | MBR<br><b>15A0</b> | MBR<br>15150 | MBR<br>15200 | Units      |
|--|------------------------|----------------|-------------|-------------|-------------|-------------|--------------------|--------------|--------------|------------|
| Maximum repetitive peak reverse voltage  |                        | Vrrm           | 35          | 45          | 50          | 60          | 100                | 150          | 200          | Volts      |
| Maximum RMS voltage  |                        | VRMS           | 25          | 32          | 35          | 42          | 70                 | 105          | 140          | Volts      |
| Maximum DC blocking voltage  |                        | VDC            | 35          | 45          | 50          | 60          | 100                | 150          | 200          | Volts      |
| Maximum average forward rectified current See Fig. 1   |                        | I(AV)          | 15.0        |             |             |             |                    |              |              | Amps       |
| Peak forward surge current 8.3ms single half<br>sine-wave superimposed on rated load<br>(JEDEC method) |                        | İFSM           | 150.0       |             |             |             |                    |              |              | Amps       |
| Maximum instantaneous forward voltage at 15 A  |                        | VF             | 0.60        |             | (           | 0.75        | 0.85               | 0. 90        | 0. 95        | Volts      |
| Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)                             | T <sub>c</sub> =25°C   | ī              | 0.2         |             |             |             |                    |              |              |            |
|  | T <sub>c</sub> = 125°C | <b>I</b> R     | 30          |             |             | 50          |                    |              |              | m <b>A</b> |
| Typical thermal resistance (Note 2)  |                        | $R_{	heta}$ JC | 3.0         |             |             |             |                    |              |              | °C/W       |
| Operating junction temperature range   |                        | TJ             | -65 to+150  |             |             |             |                    |              |              | °C         |
| Storage temperature range  |                        | TstG           | -65 to+150  |             |             |             |                    |              |              | °C         |

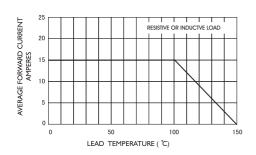
NOTE: 1. Pulse test:300us pulse width,1% duty cycle.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

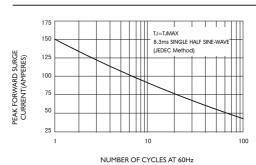
3. Thermal resistance junction to ambient

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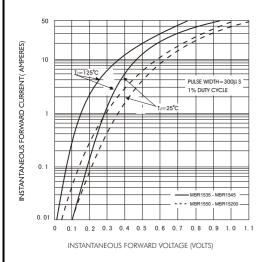
### FIG.1-FORWARD CURRENT DERATING CURVE



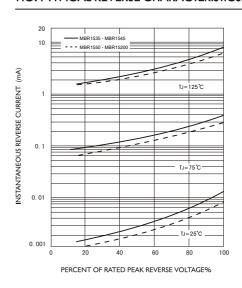
## FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



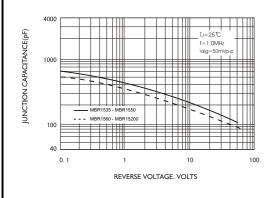
# FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



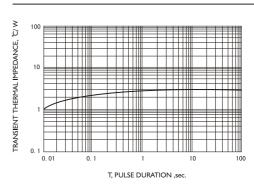
### FIG.4-TYPICAL REVERSE CHARACTERISTICS



### FIG.5-TYPICAL JUNCTION CAPACITANCE



### FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE



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